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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# 2SJ547

## Silicon P Channel MOS FET

REJ03G0894-0300

(Previous: ADE-208-658A)

Rev.3.00 Sep 07, 2005

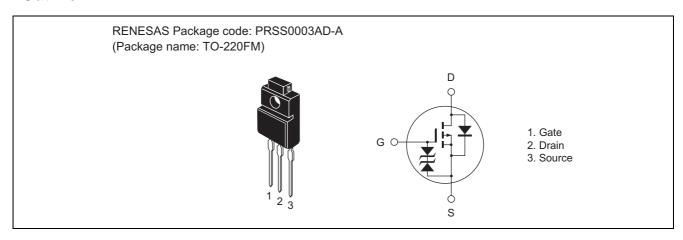
### **Description**

High speed power switching

#### **Features**

- Low on-resistance  $R_{DS \; (on)} = 0.16 \; \Omega \; typ. \label{eq:DS}$
- 4 V gate drive devices
- High speed switching

#### **Outline**



# **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit
Drain to source voltage	$V_{DSS}$	-60	V
Gate to source voltage	$V_{GSS}$	±20	V
Drain current	I <sub>D</sub>	-10	A
Drain peak current	I <sub>D (pulse)</sub> Note 1	-40	A
Body to drain diode reverse drain current	I <sub>DR</sub>	-10	А
Avalanche current	I <sub>AP</sub> Note 3	-10	А
Avalanche energy	E <sub>AR</sub> Note 3	8.5	mJ
Channel dissipation	Pch Note 2	20	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at  $Tc = 25^{\circ}C$ 

3. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

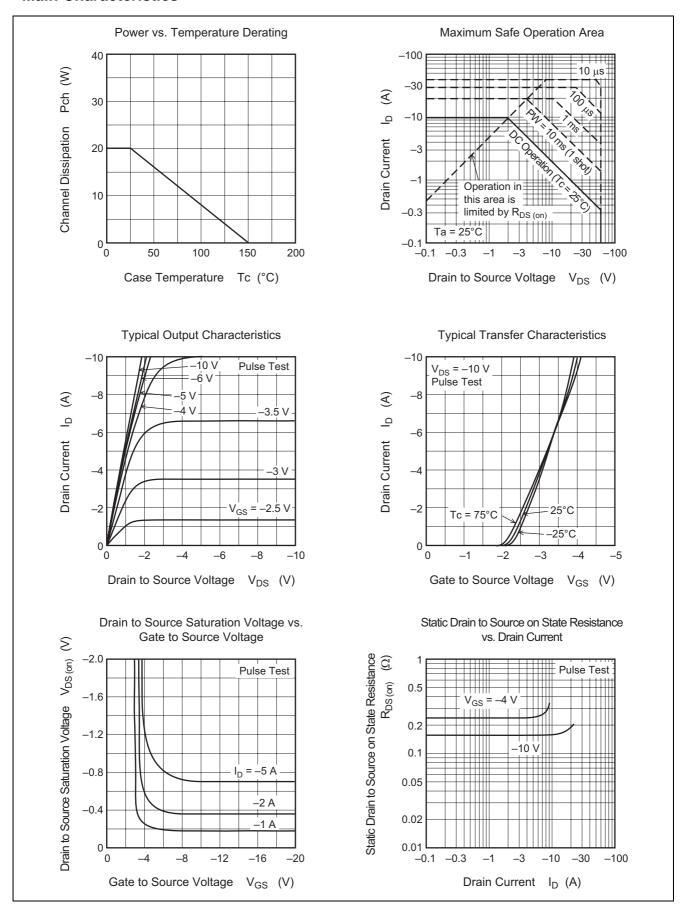
#### **Electrical Characteristics**

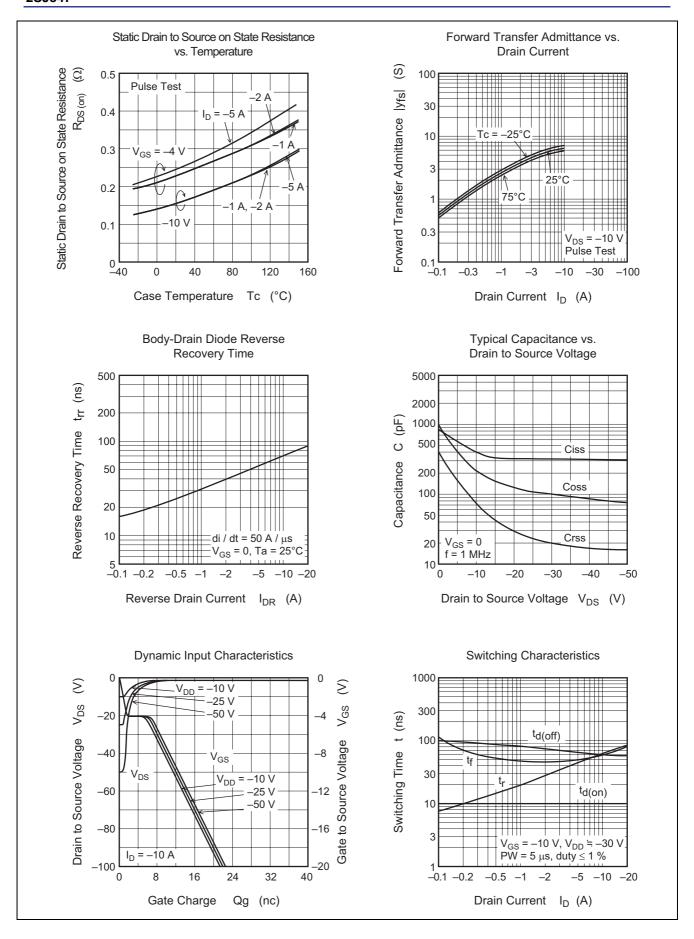
 $(Ta = 25^{\circ}C)$ 

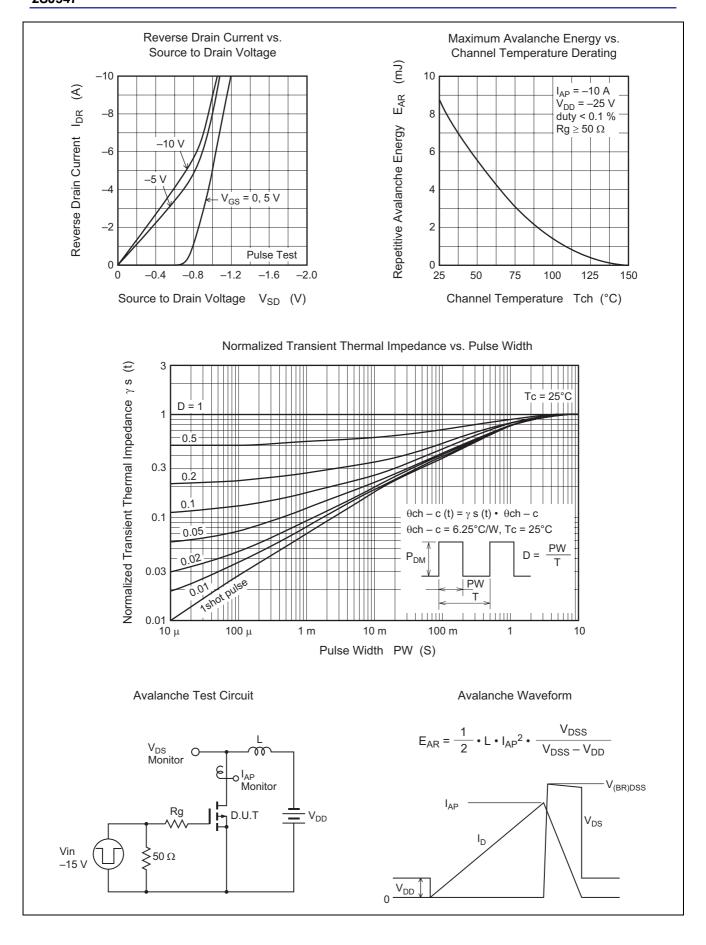
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR) DSS</sub>	-60	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V <sub>(BR) GSS</sub>	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	-10	μΑ	$V_{DS} = -60 \text{ V}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	V <sub>GS (off)</sub>	-1.0	_	-2.0	V	$I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$
Static drain to source on state resistance	R <sub>DS (on)</sub>	_	0.16	0.21	Ω	$I_D = -5 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note 4}}$
	R <sub>DS (on)</sub>		0.23	0.36	Ω	$I_D = -5 \text{ A}, V_{GS} = -4 \text{ V}^{\text{Note 4}}$
Forward transfer admittance	y <sub>fs</sub>	3.5	5.5	_	S	$I_D = -5 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note 4}}$
Input capacitance	Ciss	_	400	_	pF	$V_{DS} = -10 \text{ V}$
Output capacitance	Coss	_	220	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	75	_	pF	f = 1 MHz
Turn-on delay time	t <sub>d (on)</sub>	_	10	_	ns	V <sub>GS</sub> = -10 V
Rise time	t <sub>r</sub>	_	45	_	ns	$I_D = -5 A$
Turn-off delay time	t <sub>d (off)</sub>	_	65	_	ns	$R_L = 6 \Omega$
Fall time	t <sub>f</sub>	_	50	_	ns	
Body to drain diode forward voltage	$V_{DF}$	_	-1.2	_	V	$I_F = -10 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t <sub>rr</sub>	_	70	_	ns	$I_F = -10 \text{ A}, V_{GS} = 0$
						$di_F/dt = 50 A/\mu s$

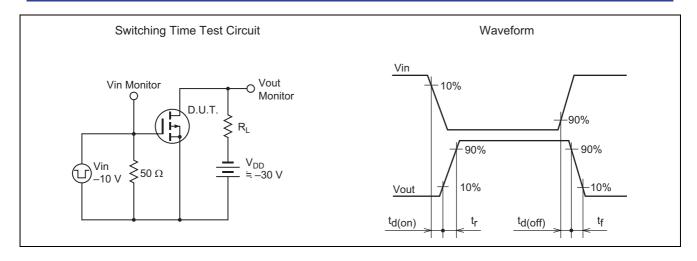
Note: 4. Pulse test

#### **Main Characteristics**

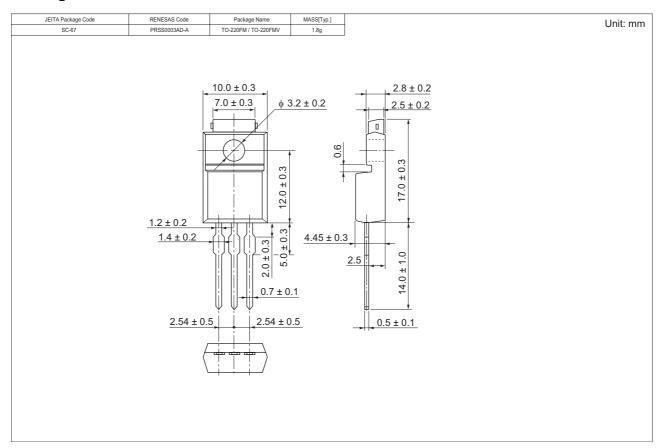








### **Package Dimensions**



### **Ordering Information**

Part Name	Quantity	Shipping Container
2SJ547-E	500 pcs	Box (Sack)

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